



Features

Low On-Resistance Low Input Capacitance Fast Switching Speed Low Input/Output Leakage

certified facilities.

Mechanical Data

Case: SOT23

DMG3414UQ

N-CHANNEL ENHANCEMENT MODE MOSFET

Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) The DMG3414UQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 gualified, PPAP capable, and manufactured in IATF 16949

https://www.diodes.com/guality/product-definitions/

Case Material: Molded Plastic, "Green" Molding Compound.

Terminals: Finish — Matte Tin Annealed over Copper Leadframe.

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020

Solderable per MIL-STD-202, Method 208 (63)

Terminals Connections: See Diagram Below

Weight: 0.008 grams (Approximate)

D

Product Summary

BVDSS	Rds(ON) Max	I _D Max T₄ = +25°C
	25mΩ @ VGs = 4.5V	4.2A
20V	29mΩ @ V _{GS} = 2.5V	4.0A
	37mΩ @ VGs = 1.8V	3.4A

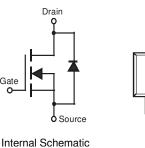
Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- **Power Management Functions**
- **DC-DC Converters**





Top View

G

Ordering Information (Note 4)

Part Number	Case	Packaging
DMG3414UQ-7	SOT23	3,000/Tape & Reel
DMG3414UQ-13	SOT23	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Gate

Marking Information

SOT2	3
MN8	ΜX

MN8 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021)M = Month (ex: 9 = September)

Date Code Key

Notes:

Sale Code Rey												
Year	2015		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	С			J	K		М	N	0	Р	B	S
0000	v		•	v		-			•			U
	Jan		Mar	Apr	May		1	Δυα	Sep	Oct	Nov	Dec
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characte	eristic		Symbol	Value	Unit
Drain-Source Voltage			VDSS	20	V
Gate-Source Voltage		V _{GSS}	±8	V	
Continuous Drain Current (Note 5)Steady State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$			ID	4.2 3.2	A
Pulsed Drain Current (Note 6)	•		Ідм	30	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.78	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$	Reja	162	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	•			•	•	•
Drain-Source Breakdown Voltage	BVDSS	20	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	_		1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_		±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						·
Gate Threshold Voltage	V _{GS(TH)}	0.5		0.9	V	$V_{DS}=V_{GS},\ I_{D}=250\mu A$
			19	25		V _{GS} = 4.5V, I _D = 8.2A
Static Drain-Source On-Resistance	RDS(ON)	—	22	29	mΩ	$V_{GS} = 2.5V, I_{D} = 3.3A$
			28	37		$V_{GS} = 1.8V, I_D = 2.0A$
Forward Transfer Admittance	Y _{fs}	_	7	_	S	$V_{DS} = 10V, I_D = 4A$
DYNAMIC CHARACTERISTICS (Note 8)						-
Input Capacitance	Ciss	_	829.9		pF	
Output Capacitance	Coss	_	85.3		pF	V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	81.2	_	pF	
Total Gate Charge	Qg	_	9.6	_	nC	
Gate-Source Charge	Qgs		1.5		nC	V _{GS} = 4.5V, V _{DS} = 10V, I _D = 8.2A
Gate-Drain Charge	Qgd		3.5		nC	
Turn-On Delay Time	tD(ON)		8.1		ns	
Turn-On Rise Time	tR		8.3		ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	tD(OFF)	_	40.1	_	ns	$R_L = 10\Omega, R_G = 6\Omega, I_D = 1A$
Turn-Off Fall Time	tF		9.6	_	ns	7

5. Device mounted on FR-4 PCB with 2oz. copper and test pulse width t \leq 10s. 6. Repetitive rating, pulse width limited by junction temperature. 7. Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to production testing.



DMG3414UQ

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T_A=150°C

T_A = 125°C T_A = 85°C

T_A = 25°C

T_A = -55°C

16

20

T_A = 85°C T_A = 25°C T_A = −55°C

1.5

12

V_{GS} = 4.5V I_D = 6.5A

8

. V_{GS} = 2.5V

I_D = 5A

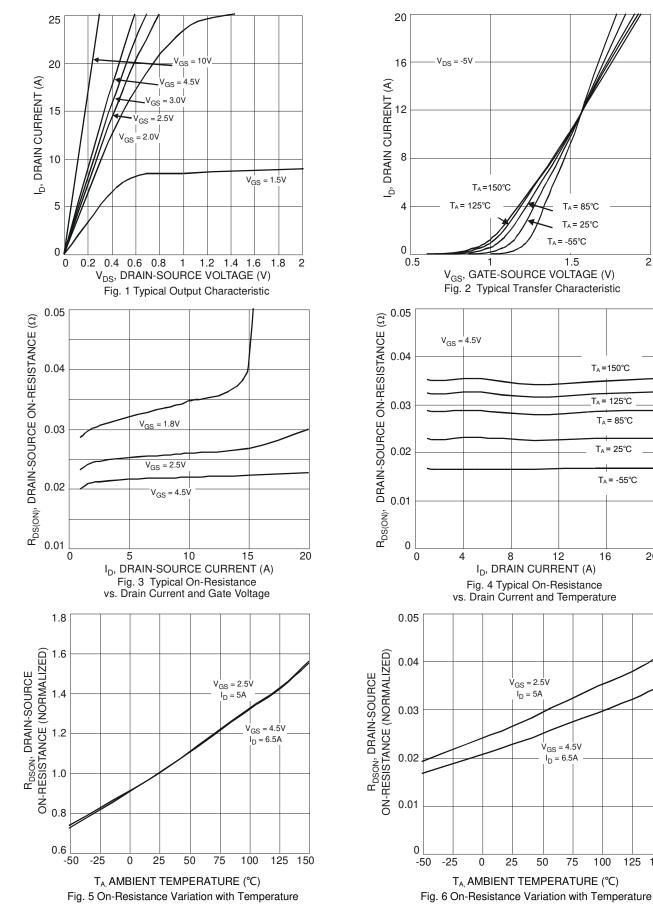
25

50

75

100

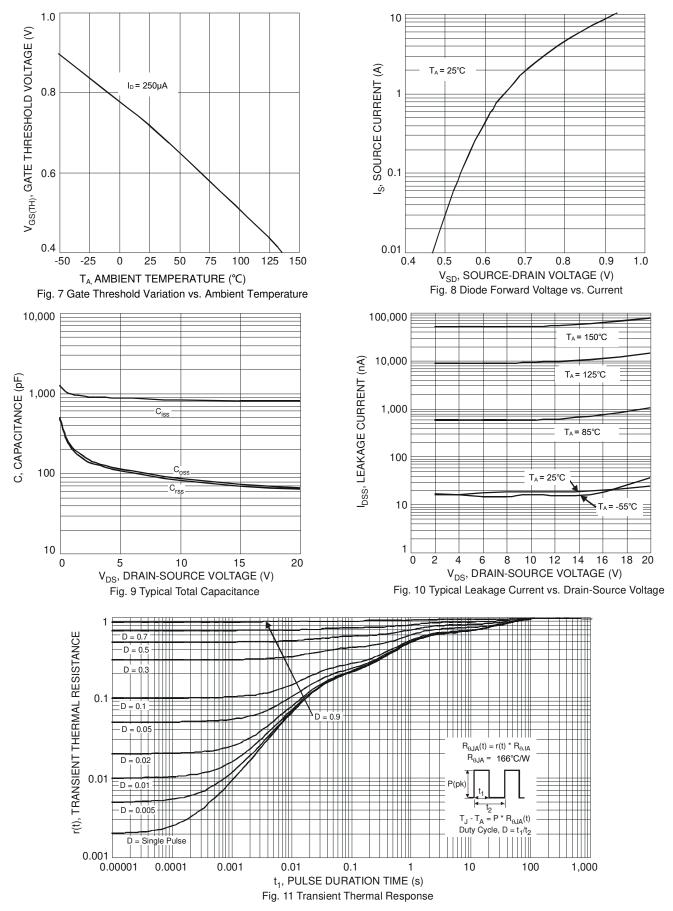
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125 150



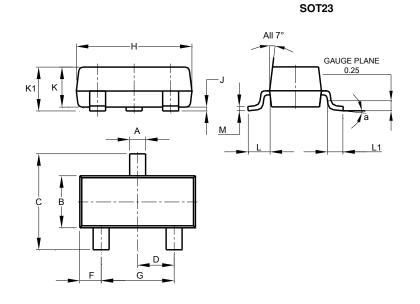
DMG3414UQ





Package Outline Dimensions

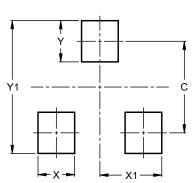
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
К	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	Dimens	ions in	mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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